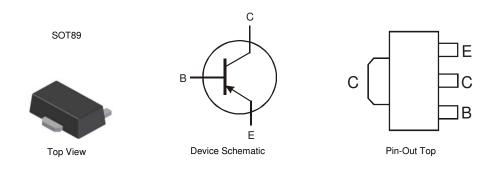


Features

- BV_{CEO} > -40V
- I_C = -4A Continuous Collector Current
- Ultra-Low Collector-Emitter Saturation Voltage
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Package: SOT89
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plates Leads.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.055 grams (Approximate)



Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS5540X-13	ZPS54	13	12mm	2500
DSS5540XTC	ZPS54	13	12mm	4000

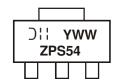
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



ZPS54 = Product Type Marking Code) | | = Manufacturer's Code Marking YWW = Date Code Marking Y = Last digit of year (ex: 2 = 2022) WW = Week code (01 - 53)



Absolute Maximum Ratings @ TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-6	V
Peak Pulse Collector Current	I _{CM}	-10	A
Repetitive Peak Pulse Collector Current (Note 5)	ICRP	-5	A
Continuous Collector Current	lc	-4	A
Peak Pulse Base Current	I _{BM}	-2	A
Continuous Base Current	IB	-1	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6) @ $T_A = 25^{\circ}C$	PD	0.9	W
Thermal Resistance, Junction to Ambient Air (Note 6) @ $T_A = 25^{\circ}C$	$R_{ ext{ heta}JA}$	139	°C/W
Power Dissipation (Note 7) @ $T_A = 25^{\circ}C$	PD	2	W
Thermal Resistance, Junction to Ambient Air (Note 7) @ $T_A = 25^{\circ}C$	$R_{ heta JA}$	62.5	°C/W
Thermal Resistance, Junction to Case (Note 6) @ $T_A = 25^{\circ}C$	$R_{\theta JC}$	17	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

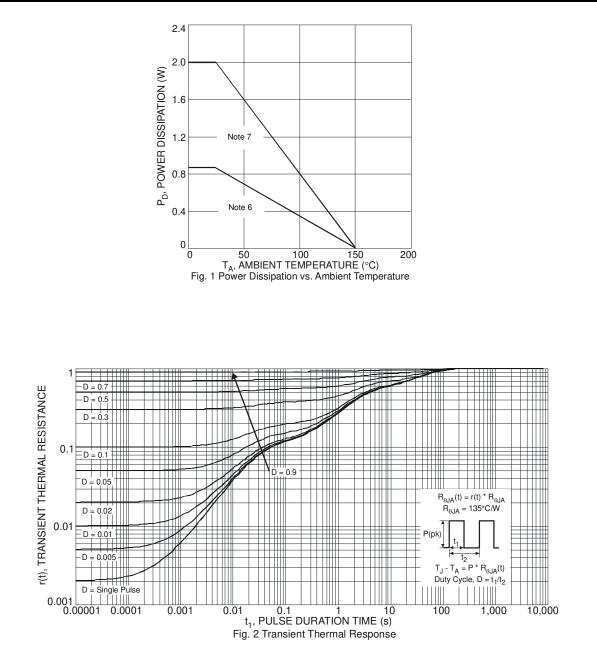
Notes:

5. Pulse width ≤ 10ms; Duty cycle ≤ 0.2
 6. For a device mounted on FR-4 PCB with minimum recommended pad layout.
 7. For a device mounted on FR-4 PCB with 1inch² copper pad layout.



DSS5540X

Thermal Characteristics and Derating Information





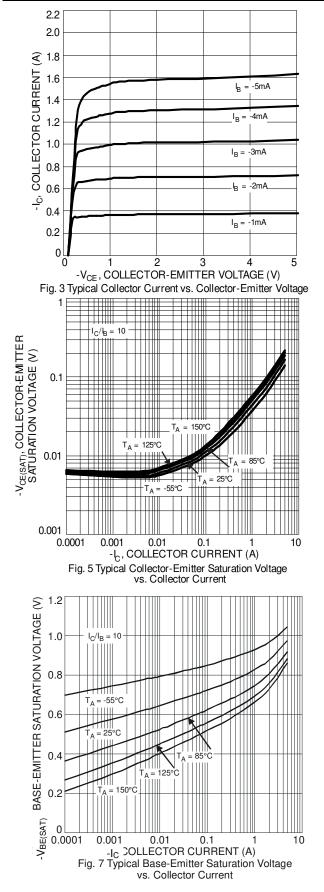
Electrical Characteristics (@ T_A = 25°C unless otherwise specified)

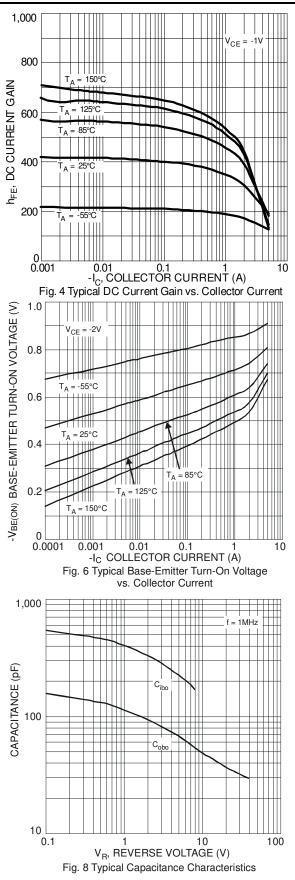
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector-Base Breakdown Voltage	BV _{CBO}	-40		_	V	I _C = -100μA	
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	-40		_	V	I _C = -10mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-6		_	V	I _E = -100μA	
Collector Deco Outoff Ourrent				-100	nA	$V_{CB} = -30V, I_E = 0$	
Collector-Base Cutoff Current	ICBO			-50	μA	V _{CB} = -30V, I _E = 0, T _A = 150°C	
Emitter-Base Cutoff Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -5V, I_{C} = 0$	
		250	_	_		V _{CE} = -2V, I _C = -0.5A	
DC Current Coin (Note 9)	h	200	350	_		V _{CE} = -2V, I _C = -1A	
DC Current Gain (Note 8)	h _{FE}	150				V _{CE} = -2V, I _C = -2A	
		50		_		V _{CE} = -2V, I _C = -5A	
		_		-120		I _C = -0.5A, I _B = -5mA	
		_		-170	mV	I _C = -1A, I _B = -10mA	
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}	_	-70	-160		I _C = -2A, I _B = -200mA	
		_	-165	-340		I _C = -4A, I _B = -200mA	
		_	-150	-375		I _C = -5A, I _B = -500mA	
Equivalent On-Resistance	R _{CE(sat)}	_	-30	-75	mΩ	I _C = -5A, I _B = -500mA	
Daga Emitter Caturation Voltage	N	_		-1.1	v	I _C = -4A, I _B = -200mA	
Base-Emitter Saturation Voltage	V _{BE(sat)}			-1.2	v	I _C = -5A, I _B = -500mA	
Base-Emitter Turn-on Voltage	V _{BE(on)}	_		-1.0	V	$V_{CE} = -2V, I_{C} = -2A$	
Transition Frequency	f _T	60		_	MHz	$V_{CE} = -10V, I_{C} = -0.1A, f = 100MHz$	
Collector Capacitance	Cc			105	pF	$V_{CB} = -10V, I_E = 0A, f = 1MHz$	
Turn-On Time	t _{on}		63	_	ns		
Delay Time	t _d		15	_	ns	1	
Rise Time	tr		48	_	ns	V _{CC} = -10V, I _C = -2A,	
Turn-Off Time	t _{off}		280		ns	$I_{B1} = -I_{B2} = -200 \text{mA}$	
Storage Time	ts		232		ns]	
Fall Time	t _f		48	—	ns		

Notes: 8. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.



Typical Electrical Characteristics (@ T_A = 25°C unless otherwise specified)



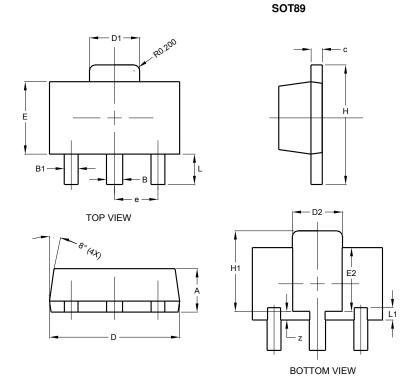


DSS5540X Document number: DS31653 Rev. 4 - 2



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

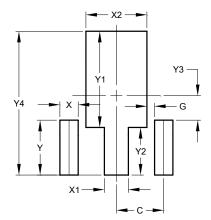


-					
SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
e	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)
С	1.500
G	0.244
Х	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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